

# International Rectifier

## 40HFL, 70HFL, 85HFL SERIES

### FAST RECOVERY DIODES

### Stud Version



#### Major Ratings and Characteristics

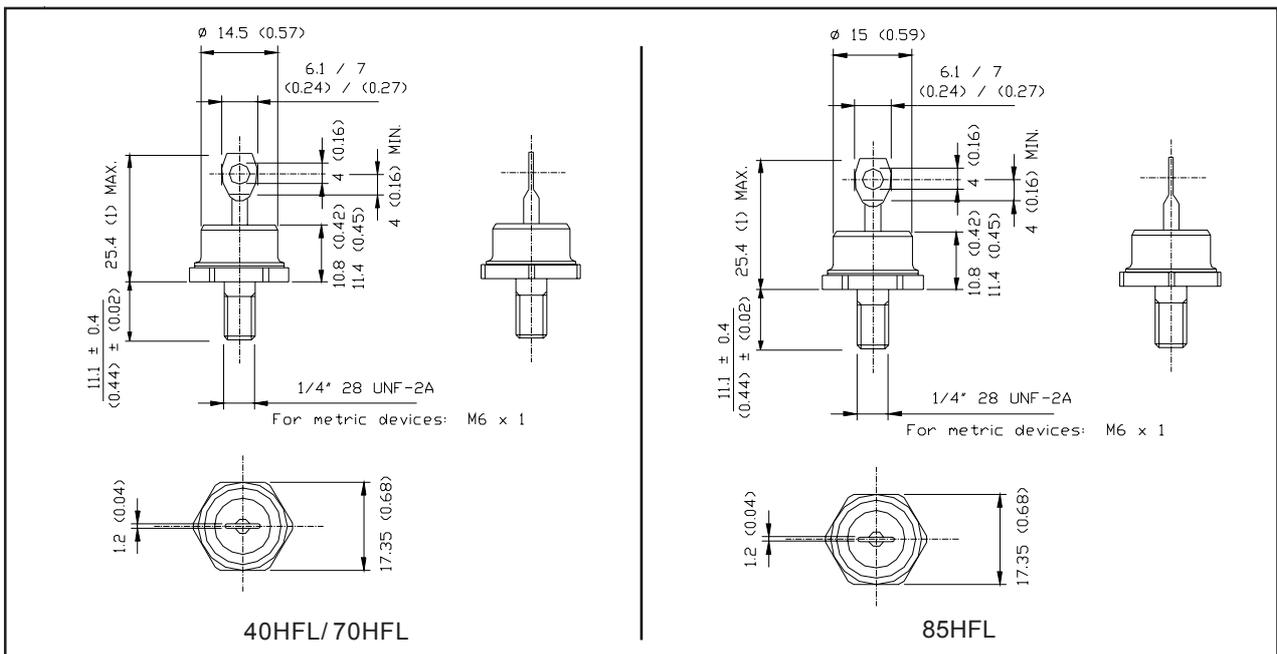
Parameters	40HFL	70HFL	85HFL	Units	
$I_{F(AV)}$	40	70	85	A	
@ Max Tc	75	75	75	A	
$I_{FSM}$	@ 50Hz	400	700	1100	A
	@ 60Hz	420	730	1151	A
$I^2t$	@ 50Hz	800	2450	6050	A <sup>2</sup> s
	@ 60Hz	730	2240	5523	A <sup>2</sup> s
$I^2vt$	11300	34650	85560	I <sup>2</sup> v/s	
$V_{RRM}$ range	100 to 1000			V	
$t_{rr}$ range	see table			ns	
$T_j$ range	- 40 to 125			°C	

#### Description

This range of fast recovery diodes is designed for applications in DC power supplies, inverters, converters, choppers, ultrasonic systems and for use as a free wheeling diode.

#### Features

- Short reverse recovery time
- Low stored charge
- Wide current range
- Excellent surge capabilities
- Stud cathode and stud anode versions
- Types up to 1000V<sub>RRM</sub>



**ELECTRICAL SPECIFICATIONS**

**Reverse voltage ratings**

Part number ①	$V_{RRM}$ , Maximum peak repetitive reverse voltage $T_J = -40$ to $125^\circ\text{C}$	$V_{RSM}$ , Maximum peak non-repetitive reverse voltage $T_J = 25$ to $125^\circ\text{C}$	$I_{FRM}$ Maximum peak reverse current at rated $V_{RRM}$	
	V	V	$T_J = 25^\circ\text{C}$ mA	$T_J = 125^\circ\text{C}$ mA
40HFL10S02, 40HFL10S05, 40HFL10S10	100	150	0.1	10
40HFL20S02, 40HFL20S05, 40HFL20S10	200	300	0.1	10
40HFL40S02, 40HFL40S05, 40HFL40S10	400	500	0.1	10
40HFL60S02, 40HFL60S05, 40HFL60S10	600	700	0.1	10
40HFL80S05, 40HFL80S10	800	900	0.1	10
40HFL100S05, 40HFL100S10	1000	1100	0.1	10
70HFL10S02, 70HFL10S05, 70HFL10S10	100	150	0.1	15
70HFL20S02, 70HFL20S05, 70HFL20S10	200	300	0.1	15
70HFL40S02, 70HFL40S05, 70HFL40S10	400	500	0.1	15
70HFL60S02, 70HFL60S05, 70HFL60S10	600	700	0.1	15
70HFL80S05, 70HFL80S10	800	900	0.1	15
70HFL100S05, 70HFL100S10	1000	1100	0.1	15
85HFL10S02, 85HFL10S05, 85HFL10S10	100	150	0.1	20
85HFL20S02, 85HFL20S05, 85HFL20S10	200	300	0.1	20
85HFL40S02, 85HFL40S05, 85HFL40S10	400	500	0.1	20
85HFL60S02, 85HFL60S05, 85HFL60S10	600	700	0.1	20
85HFL80S05, 85HFL80S10	800	900	0.1	20
85HFL100S05, 85HFL100S10	1000	1100	0.1	20

① Types listed are cathode case, for anode case add "R" to code, i.e. 40HFLR20S02, 85HFLR100S05 etc.

**Reverse recovery characteristics**

	40HFL...			70HFL...			85HFL...			Units	Conditions
	S02	S05	S10	S02	S05	S10	S02	S05	S10		
$t_{rr}$ Typical reverse recovery time	70	180	350	60	150	290	50	120	270	ns	$T_J = 25^\circ\text{C}$ , $I_F = 1\text{A}$ to $V_R = 30\text{V}$ $-di_F/dt = 100\text{A}/\mu\text{s}$
	200	500	1000	200	500	1000	200	500	1000	ns	$T_J = 25^\circ\text{C}$ , $-di_F/dt = 25\text{A}/\mu\text{s}$ $I_{FM} = \tau \times \text{rated } I_{F(AV)}$
$Q_{RR}$ Typical reverse recovered charge	160	750	3100	90	500	1600	70	340	1350	nC	$T_J = 25^\circ\text{C}$ , $I_F = 1\text{A}$ to $V_R = 30\text{V}$ $-di_F/dt = 100\text{A}/\mu\text{s}$
	240	1300	6000	240	1300	6000	240	1300	6000	nC	$T_J = 25^\circ\text{C}$ , $-di_F/dt = 25\text{A}/\mu\text{s}$ $I_{FM} = \tau \times \text{rated } I_{F(AV)}$

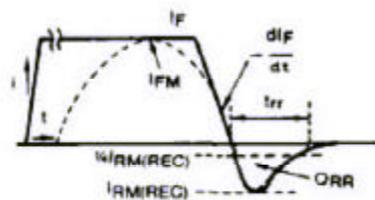
**Forward conduction**

	40HFL	70HFL	85HFL	Units	Conditions
$I_{F(AV)}$ Maximum average forward current	40	70	85	A	$180^\circ\text{C}$ conduction, half sine wave, max. $T_C = 75^\circ\text{C}$
$I_{F(RMS)}$ Maximum RMS forward current	63	110	134	A	
$I_{FRM}$ Maximum peak repetitive forward current	220	380	470	A	Sinusoidal half wave, $30^\circ$ conduction
$I_{FSM}$ Maximum peak, one cycle non-repetitive forward current	400	700	1100	A	$t = 10\text{ms}$ Sinusoidal half-wave 100% $V_{RRM}$ reapplied, initial $T_J = T_{J \text{ max}}$
	420	730	1151	A	$t = 8.3\text{ms}$
	475	830	1308	A	$t = 10\text{ms}$ Sinusoidal half-wave no voltage reapplied, initial $T_J = T_{J \text{ max}}$
	500	870	1369	A	$t = 8.3\text{ms}$
$I^2t$ Maximum $I^2t$ for fusing	800	2450	6050	$\text{A}^2\text{s}$	$t = 10\text{ms}$ 100% $V_{RRM}$ reapplied initial $T_J = T_{J \text{ max}}$
	730	2240	5523	$\text{A}^2\text{s}$	$t = 8.3\text{ms}$
	1130	3460	8556	$\text{A}^2\text{s}$	$t = 10\text{ms}$ No voltage reapplied initial $T_J = T_{J \text{ max}}$
	1030	3160	7810	$\text{A}^2\text{s}$	$t = 8.3\text{ms}$
$I^2\sqrt{t}$ Maximum $I^2\sqrt{t}$ for fusing ①	11 300	34 650	85 560	$\text{A}^2/\sqrt{\text{s}}$	$t = 0.1$ to $10\text{ms}$ , no voltage reapplied
$V_{F(TO)}$ Maximum value of threshold voltage	1.081	1.085	1.128	V	$T_J = 125^\circ\text{C}$
$r_F$ Maximum value of forward slope resistance	6.33	3.40	2.11	$\text{m}\Omega$	
$V_{FM}$ Maximum peak forward voltage	1.95	1.85	1.75	V	$T_J = 25^\circ\text{C}$ , $I_{FM} = \tau \times I_{F(AV)}$

①  $I^2t$  for time  $t_x = I^2\sqrt{t} + \sqrt{t_x}$ .

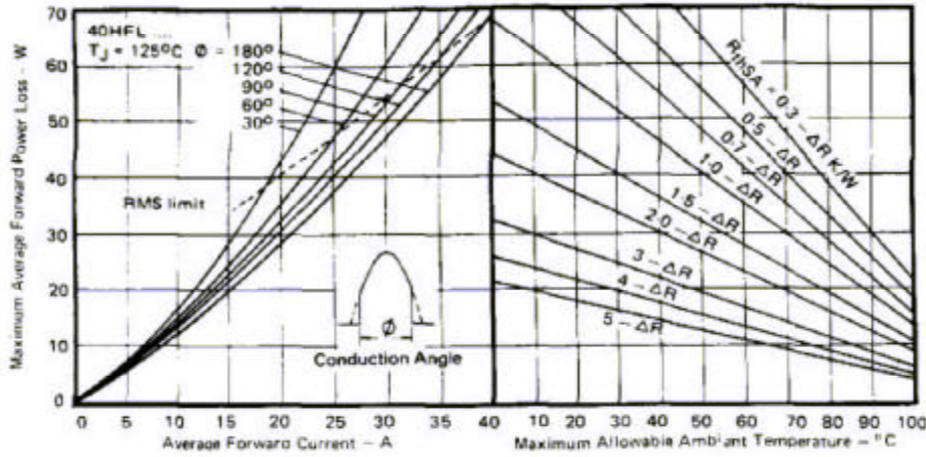
**THERMAL AND MECHANICAL SPECIFICATIONS**

		40HFL...	70HFL...	85HFL...	Units	Conditions
$T_j$	Junction operating temperature range	-40 to 125			°C	
$T_{stg}$	Storage temperature range	-40 to 150			°C	
$R_{thJC}$	Maximum internal thermal resistance, junction to case	0.60	0.36	0.30	K/W	DC operation
$R_{thCS}$	Maximum thermal resistance, case to heatsink	0.25			K/W	Mounting surface, smooth, flat and greased
$T$	Mounting torque 10%	to nut		20 (27)	lbf·in	Lubricated threads (non-lubricated threads)
				0.23 (0.29)	kgf·m	
				2.2 (2.7)	N·m	
	to device		22	lbf·in		
			0.25	kgf·m		
			2.5	N·m		
$wt$	Approximate weight	25 (0.88)			g (oz)	
	Outline	DO-203AB (DO-5)				JEDEC



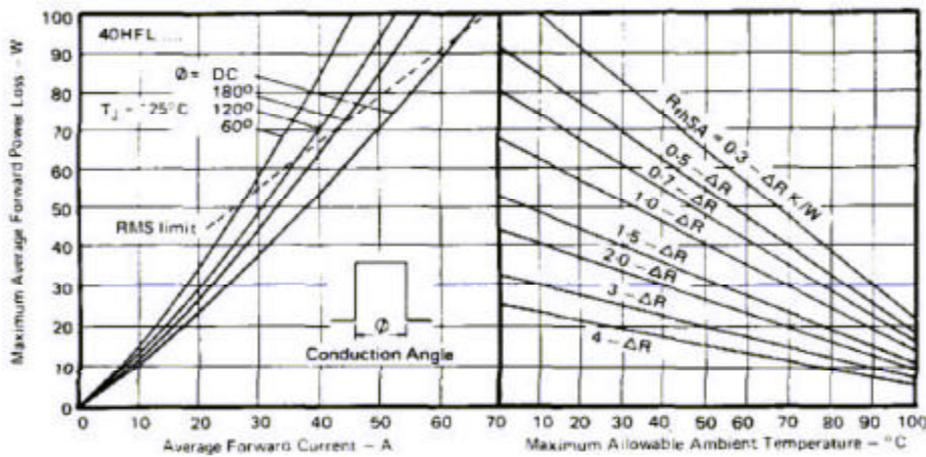
- $I_F, I_{FM}$  = Peak forward current prior to commutation
- $-dI_F/dt$  = Rate of fall of forward current
- $I_{RM(REC)}$  = Peak reverse recovery current
- $t_{rr}$  = Reverse recovery time
- ORR = Reverse recovered charge

**Fig. 1 — Reverse Recovery Time Test Waveform**



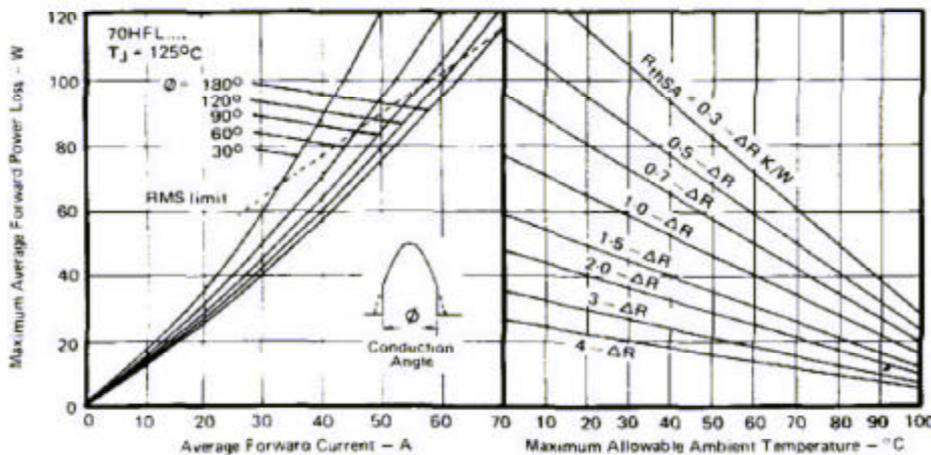
Conduction angle - $\phi$	$\Delta R$	K/W
180°	0.14	
120°	0.15	
90°	0.20	
60°	0.31	
30°	0.53	

Fig. 2 - Current Rating Nomogram (Sinusoidal Waveforms), 40HFL Series



Conduction angle - $\phi$	$\Delta R$	K/W
DC	0	
180°	0.08	
120°	0.14	
90°	0.30	

Fig. 3 - Current Rating Nomogram (Rectangular Waveforms), 40HFL Series



Conduction angle - $\phi$	$\Delta R$	K/W
180°	0.08	
120°	0.09	
90°	0.12	
60°	0.18	
30°	0.32	

Fig. 4 - Current Rating Nomogram (Sinusoidal Waveforms), 70HFL Series

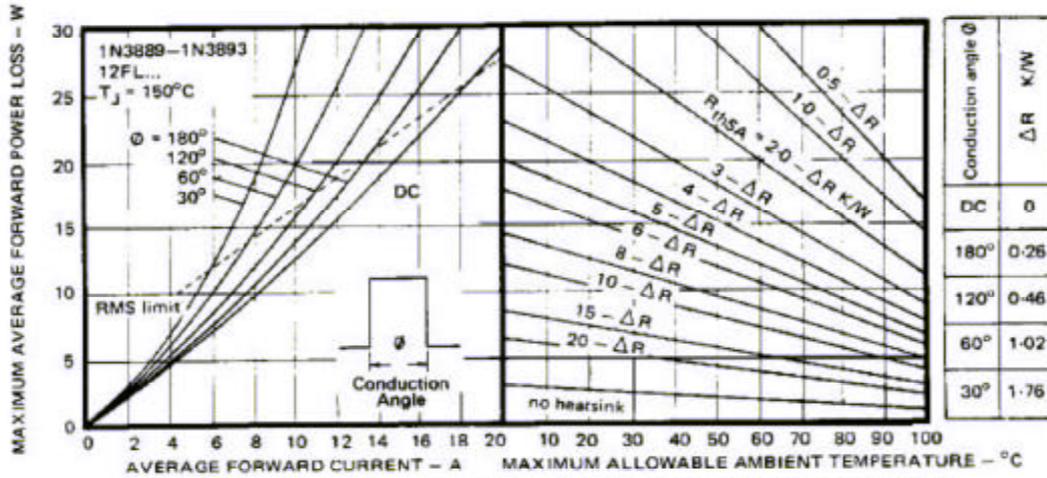


Fig. 8 - Current Rating Nomogram (Rectangular Waveforms), 1N3889 and 12FL Series

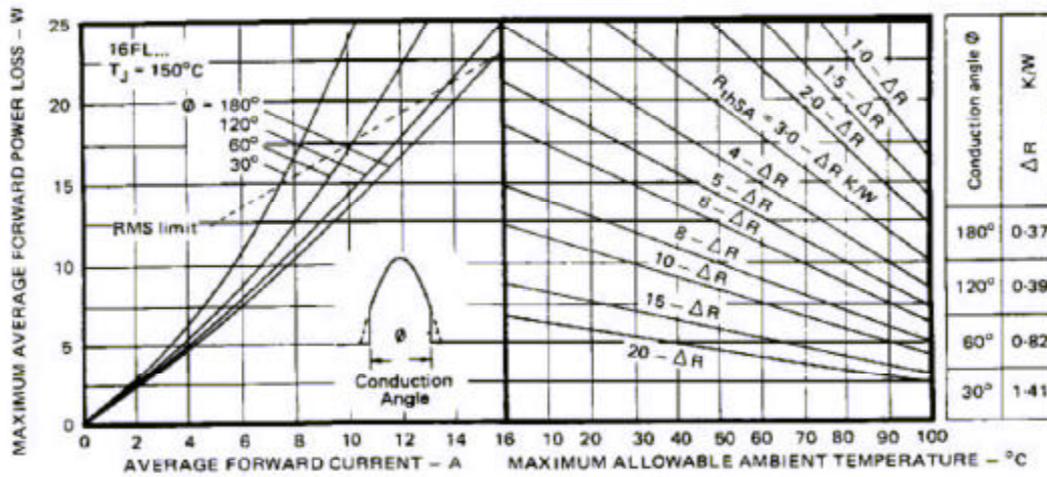


Fig. 9 - Current Rating Nomogram (Sinusoidal Waveforms), 16FL Series

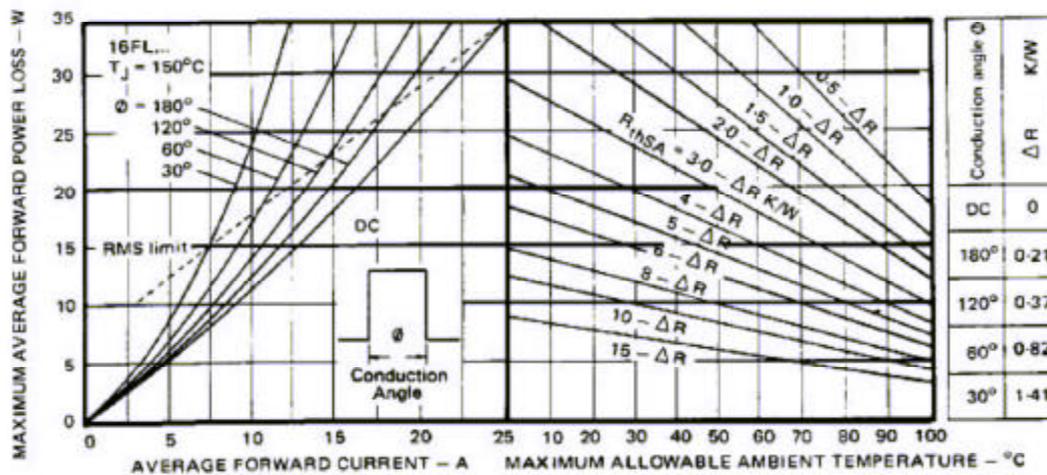


Fig. 10 - Current Rating Nomogram (Rectangular Waveforms), 16FL Series

40HFL, 70HFL, 85HFL Series

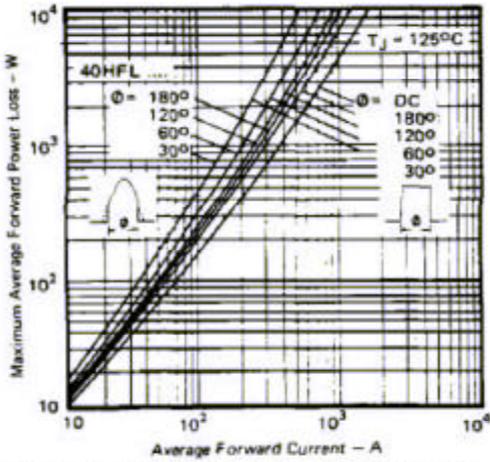


Fig. 8 - Maximum High Level Forward Power Loss Vs. Average Forward Current, 40HFL Series

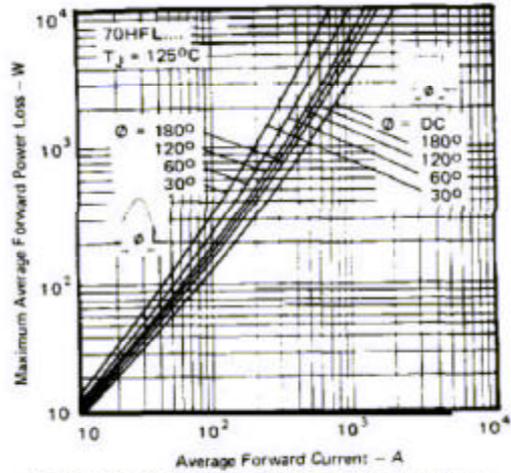


Fig. 9 - Maximum High Level Forward Power Loss Vs. Average Forward Current, 70HFL Series

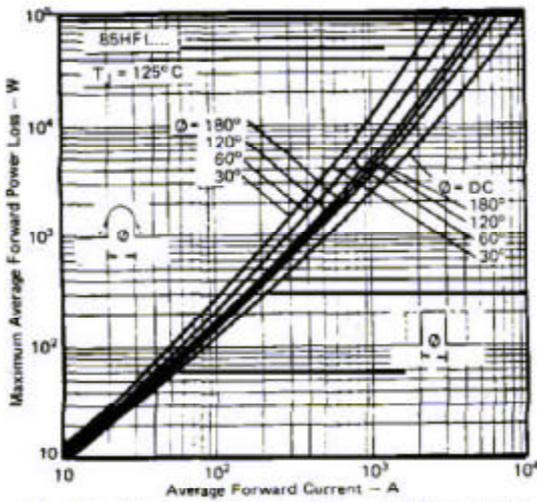


Fig. 10 - Maximum High Level Forward Power Loss Vs. Average Forward Current, 85HFL Series

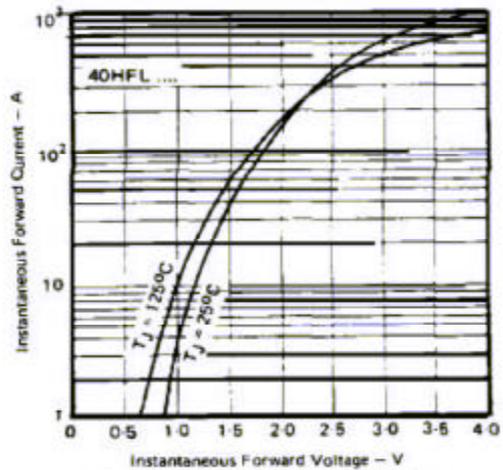


Fig. 11 - Maximum Forward Voltage Vs. Forward Current, 40HFL Series

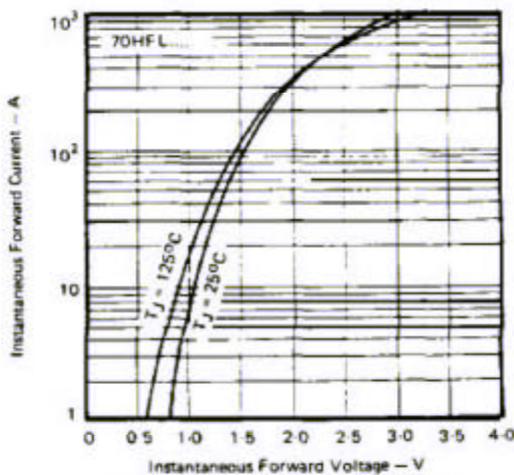


Fig. 12 - Maximum Forward Voltage Vs. Forward Current, 70HFL Series

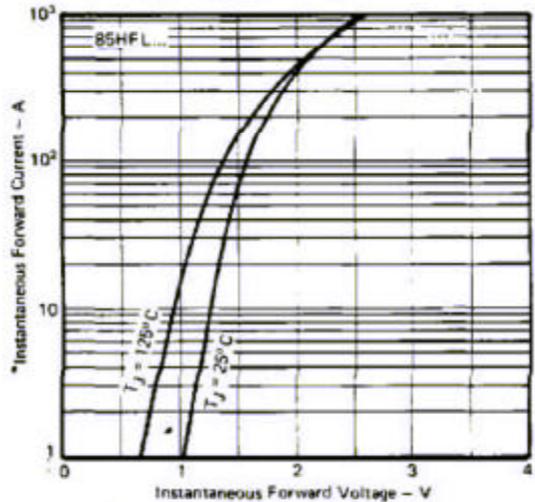


Fig. 13 - Maximum Forward Voltage Vs. Forward Current, 85HFL Series

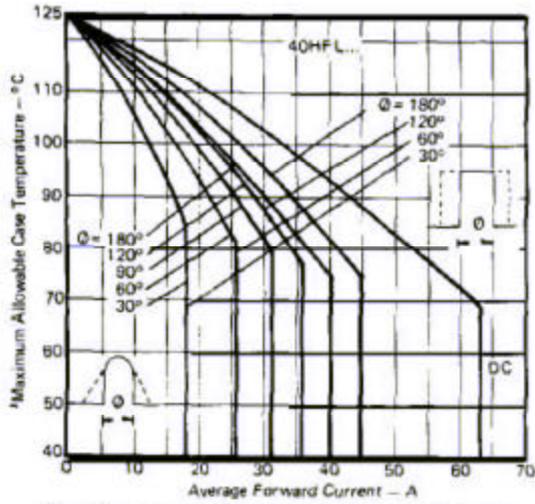


Fig. 14 — Average Forward Current Vs. Maximum Allowable Case Temperature, 40HFL Series

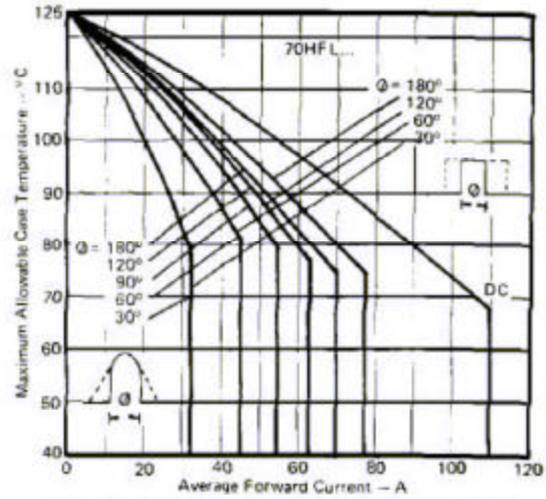


Fig. 15 — Average Forward Current Vs. Maximum Allowable Case Temperature, 70HFL Series

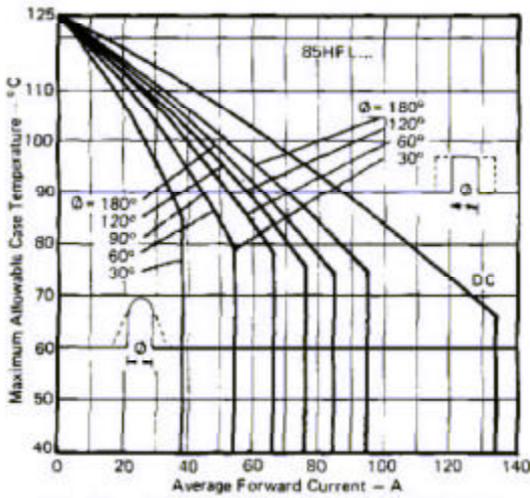


Fig. 16 — Average Forward Current Vs. Maximum Allowable Case Temperature, 85HFL Series

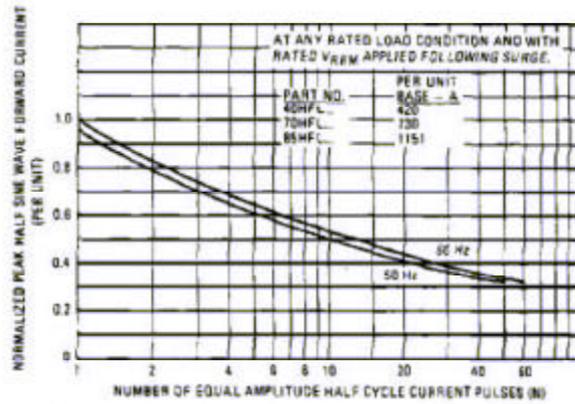


Fig. 17 — Maximum Non-Repetitive Surge Current Vs. Number of Current Pulses, All Series

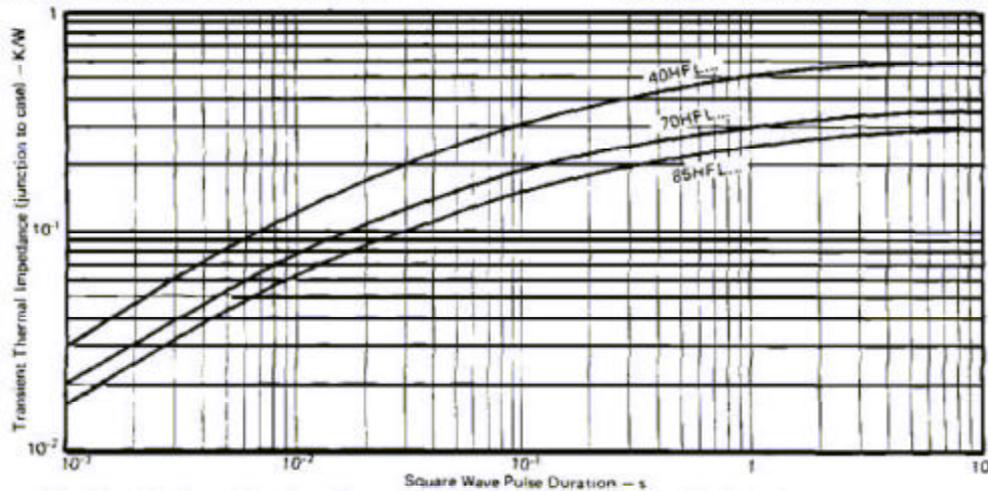


Fig. 18 — Maximum Transient Thermal Impedance, Junction-to-Case Vs. Pulse Duration, All Series

40HFL, 70HFL, 85HFL Series

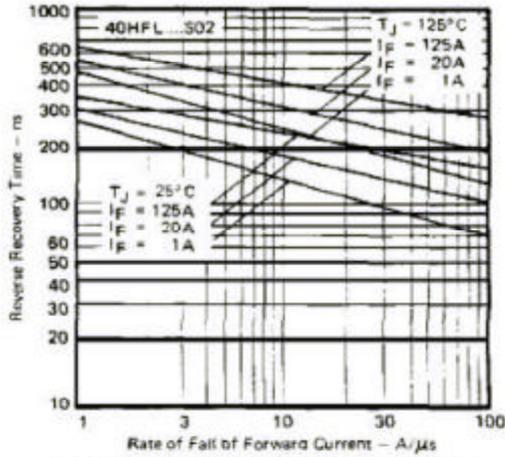


Fig. 19 — Typical Reverse Recovery Time Vs. Rate of Fall of Forward Current, 40HFL...S02 Series

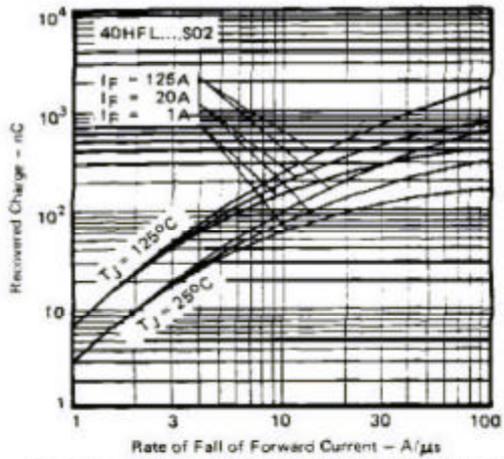


Fig. 20 — Typical Recovered Charge Vs. Rate of Fall of Forward Current, 40HFL...S02 Series

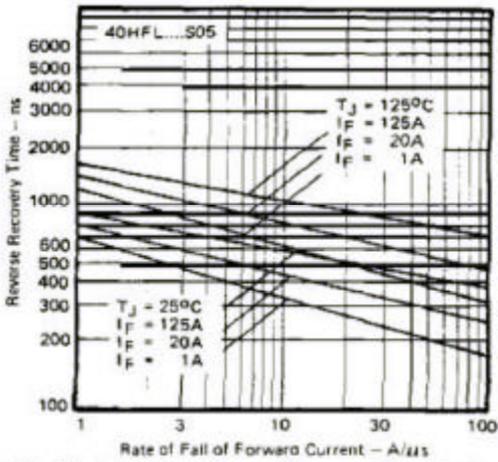


Fig. 21 — Typical Reverse Recovery Time Vs. Rate of Fall of Forward Current, 40HFL...S05 Series

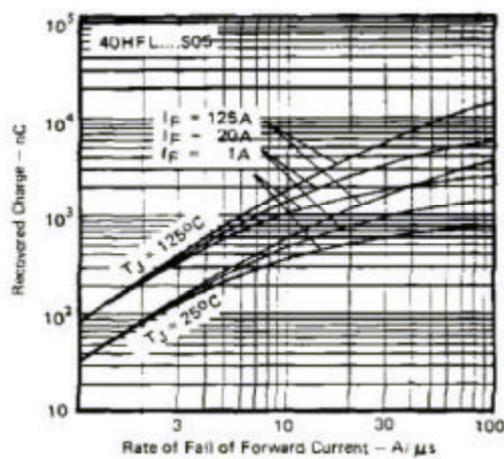


Fig. 22 — Typical Recovered Charge Vs. Rate of Fall of Forward Current, 40HFL...S05 Series

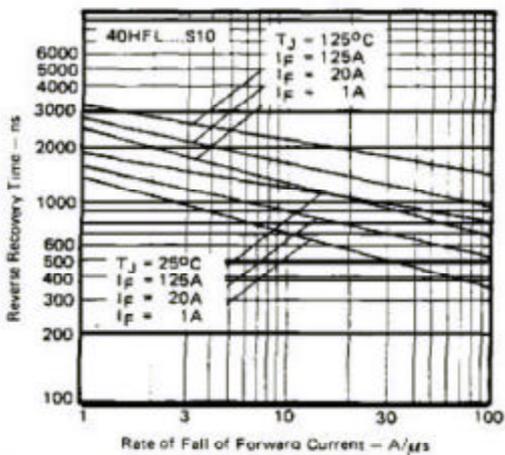


Fig. 23 — Typical Reverse Recovery Time Vs. Rate of Fall of Forward Current, 40HFL...S10 Series

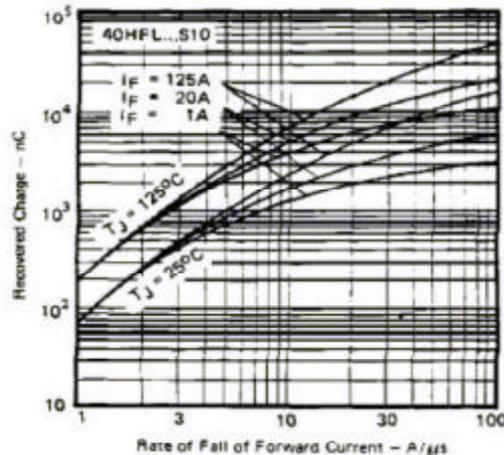


Fig. 24 — Typical Recovered Charge Vs. Rate of Fall of Forward Current, 40HFL...S10 Series

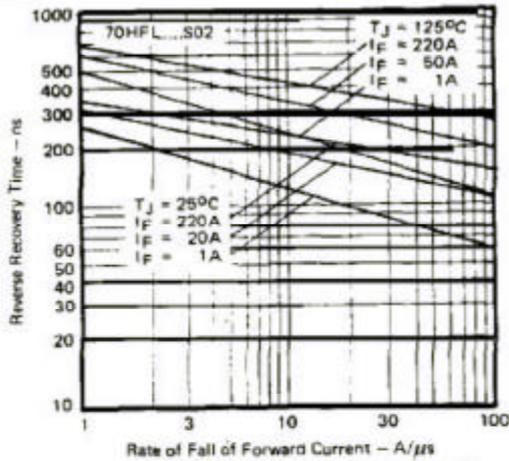


Fig. 25 — Typical Reverse Recovery Time Vs. Rate of Fall of Forward Current, 70HFL...S02 Series

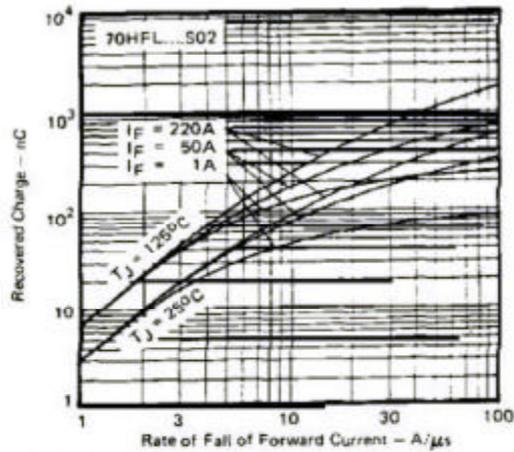


Fig. 26 — Typical Recovered Charge Vs. Rate of Fall of Forward Current, 70HFL...S02 Series

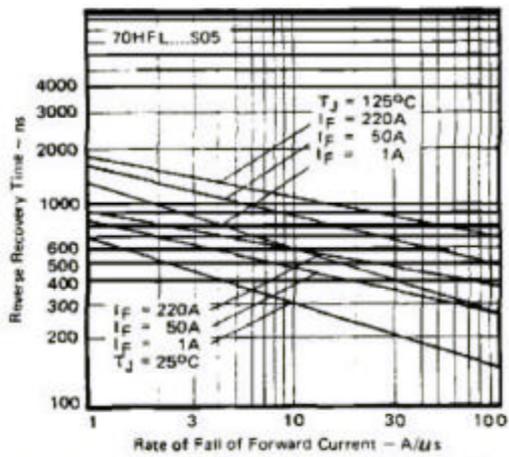


Fig. 27 — Typical Reverse Recovery Time Vs. Rate of Fall of Forward Current, 70HFL...S05 Series

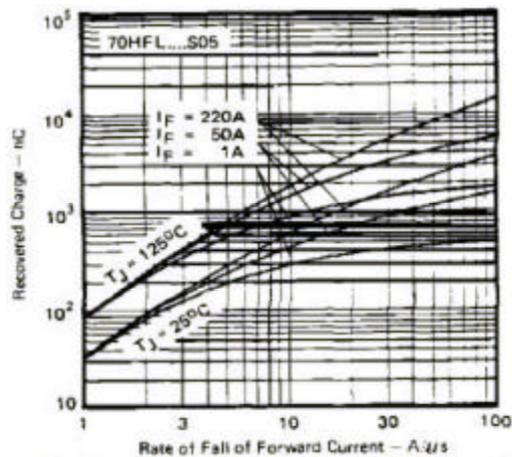


Fig. 28 — Typical Recovered Charge Vs. Rate of Fall of Forward Current, 70HFL...S05 Series

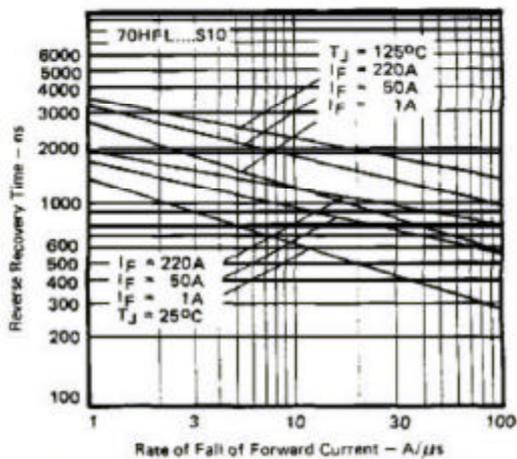


Fig. 29 — Typical Reverse Recovery Time Vs. Rate of Fall of Forward Current, 70HFL...S10 Series

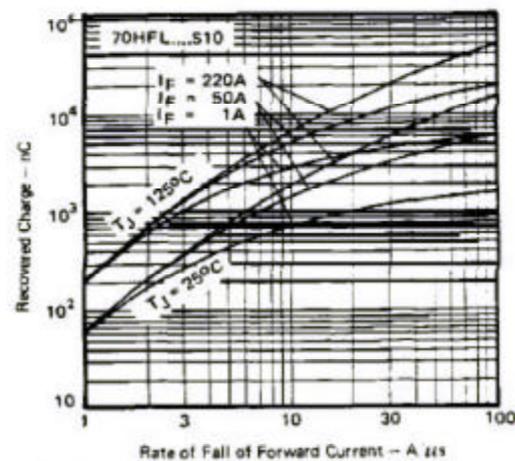


Fig. 30 — Typical Recovered Charge Vs. Rate of Fall of Forward Current, 70HFL...S10 Series

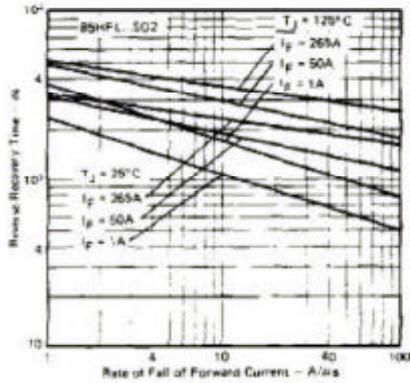


Fig. 31 – Typical Reverse Recovery Time Vs. Rate of Fall of Forward Current, 85HFL\_\_S02 Series

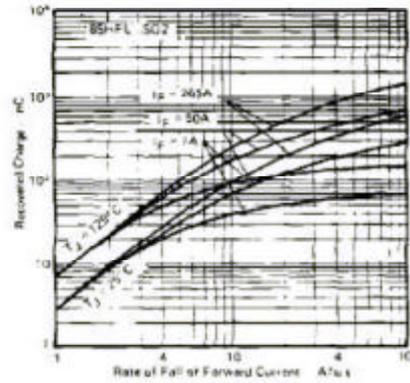


Fig. 32 – Typical Recovered Charge Vs. Rate of Fall of Forward Current, 85HFL\_\_S02 Series

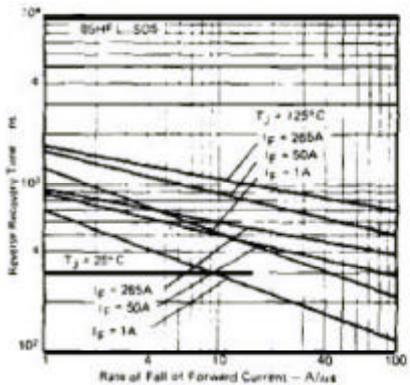


Fig. 33 – Typical Reverse Recovery Time Vs. Rate of Fall of Forward Current, 85HFL\_\_S05 Series

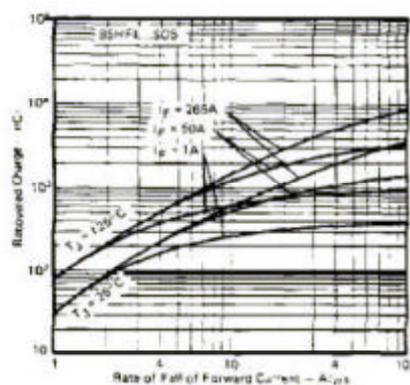


Fig. 34 – Typical Recovered Charge Vs. Rate of Fall of Forward Current, 85HFL\_\_S05 Series

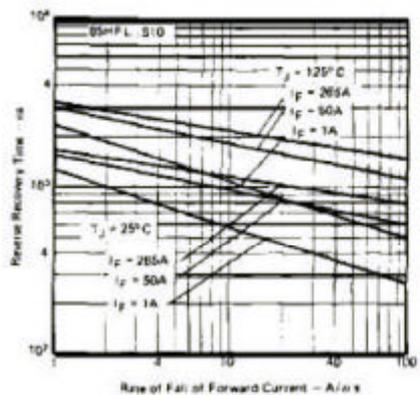


Fig. 35 – Typical Reverse Recovery Time Vs. Rate of Fall of Forward Current, 85HFL\_\_S10 Series

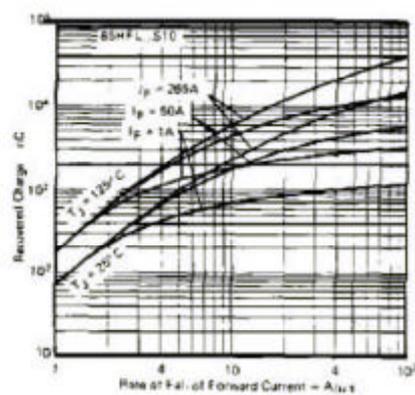


Fig. 36 – Typical Recovered Charge Vs. Rate of Fall of Forward Current, 85HFL\_\_S10 Series

Компания «Life Electronics» занимается поставками электронных компонентов импортного и отечественного производства от производителей и со складов крупных дистрибьюторов Европы, Америки и Азии.

С конца 2013 года компания активно расширяет линейку поставок компонентов по направлению коаксиальный кабель, кварцевые генераторы и конденсаторы (керамические, пленочные, электролитические), за счёт заключения дистрибьюторских договоров

Мы предлагаем:

- Конкурентоспособные цены и скидки постоянным клиентам.
- Специальные условия для постоянных клиентов.
- Подбор аналогов.
- Поставку компонентов в любых объемах, удовлетворяющих вашим потребностям.
- Приемлемые сроки поставки, возможна ускоренная поставка.
- Доставку товара в любую точку России и стран СНГ.
- Комплексную поставку.
- Работу по проектам и поставку образцов.
- Формирование склада под заказчика.
- Сертификаты соответствия на поставляемую продукцию (по желанию клиента).
- Тестирование поставляемой продукции.
- Поставку компонентов, требующих военную и космическую приемку.
- Входной контроль качества.
- Наличие сертификата ISO.

В составе нашей компании организован Конструкторский отдел, призванный помогать разработчикам, и инженерам.

Конструкторский отдел помогает осуществить:

- Регистрацию проекта у производителя компонентов.
- Техническую поддержку проекта.
- Защиту от снятия компонента с производства.
- Оценку стоимости проекта по компонентам.
- Изготовление тестовой платы монтаж и пусконаладочные работы.



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